

## 2N4123



## **NPN General Purpose Amplifier**

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 100 mA.

## **Absolute Maximum Ratings\***

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CEO}$	Collector-Emitter Voltage	30	V
V <sub>CBO</sub>	Collector-Base Voltage	40	V
V <sub>EBO</sub>	Emitter-Base Voltage	5.0	V
Ic	Collector Current - Continuous	200	mA
T <sub>J</sub> , T <sub>stg</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

## Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	Max	Units
		2N4123	
P <sub>D</sub>	Total Device Dissipation Derate above 25°C	625 5.0	mW mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W

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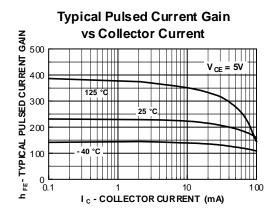
# NPN General Purpose Amplifier (continued)

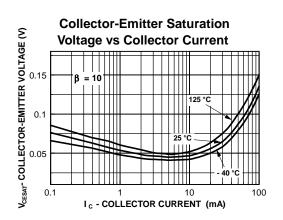
Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHA	RACTERISTICS				
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage*	$I_C = 1.0 \text{ mA}, I_B = 0$	30		V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	$I_C = 10  \mu A, I_E = 0$	40		V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_E = 10  \mu A, I_C = 0$	5.0		V
I <sub>CBO</sub>	Collector Cutoff Current	$V_{CB} = 20 \text{ V}, I_{E} = 0$		50	nA
I <sub>EBO</sub>	Emitter Cutoff Current	$V_{EB} = 3.0 \text{ V}, I_{C} = 0$		50	nA
ON CHAR	RACTERISTICS*				
h <sub>FE</sub>	DC Current Gain	$V_{CE} = 1.0 \text{ V}, I_{C} = 2.0 \text{ mA}$	50	150	
.,	Collegeor Emitter Coturation Voltage	$V_{CE} = 1.0 \text{ V}, I_{C} = 50 \text{ mA}$	25	0.3	V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	$I_C = 50 \text{ mA}, I_B = 5.0 \text{ mA}$			
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	$I_C = 50 \text{ mA}, I_B = 5.0 \text{ mA}$		0.95	V
SMALL S	IGNAL CHARACTERISTICS				
C <sub>ob</sub>	Output Capacitance	$V_{CB} = 5.0 \text{ V}, f = 100 \text{ kHz}$		4.0	pF
C <sub>ib</sub>	Input Capacitance	V <sub>EB</sub> = 0.5 V, f = 0.1 MHz		8.0	pF
h <sub>fe</sub>	Small-Signal Current Gain	$I_C = 2.0 \text{ mA}, V_{CE} = 10 \text{ V},$			
		f = 1.0 kHz	50	200	
		1 40 4 1/ 00 1/			
		$I_C = 10 \text{ mA}, V_{CE} = 20 \text{ V},$ f = 100  MHz	2.5		
f <sub>T</sub>	Current Gain - Bandwidth Product	I <sub>C</sub> = 10 mA, V <sub>CE</sub> = 20 V, f = 100 MHz I <sub>C</sub> = 10 mA, V <sub>CE</sub> = 20 V	2.5 250		MHz
•		f = 100  MHz $I_C = 10 \text{ mA}, V_{CE} = 20 \text{ V}$ f = 100  MHz			
f <sub>T</sub>	Current Gain - Bandwidth Product  Noise Figure	f = 100  MHz $I_C = 10 \text{ mA}, V_{CE} = 20 \text{ V}$		6.0	MHz dB

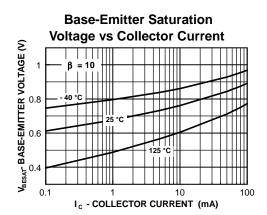
<sup>\*</sup>Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2.0%

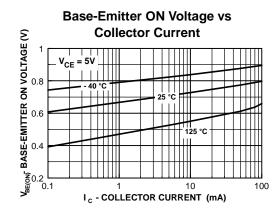
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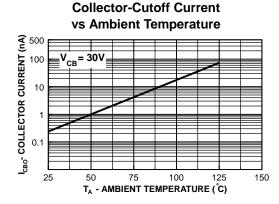
## **Typical Characteristics**

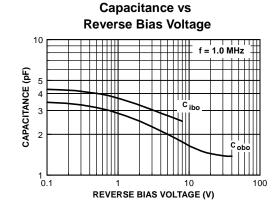






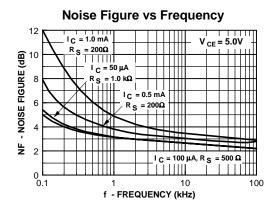


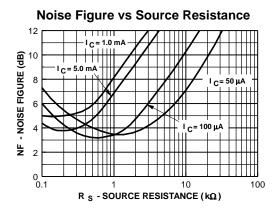


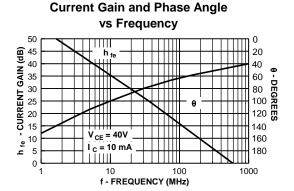


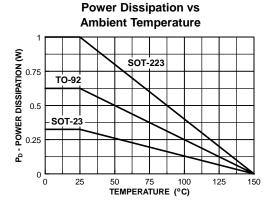
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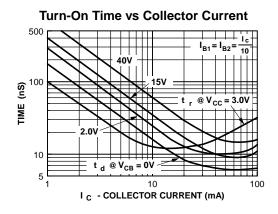
## Typical Characteristics (continued)

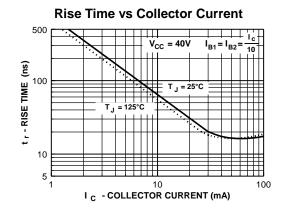








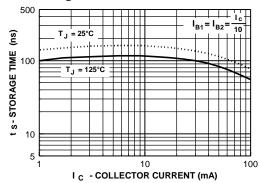




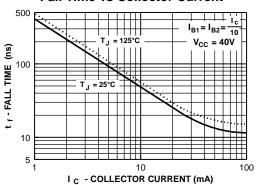
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## Typical Characteristics (continued)

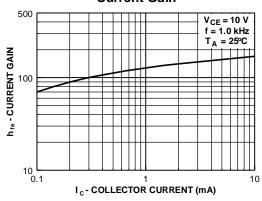




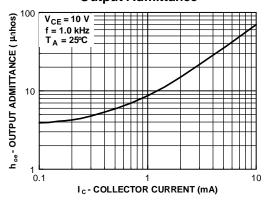
#### **Fall Time vs Collector Current**



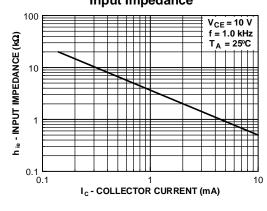
**Current Gain** 



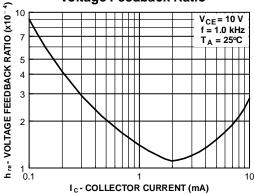
**Output Admittance** 



Input Impedance



Voltage Feedback Ratio



(continued)

## **Test Circuits**

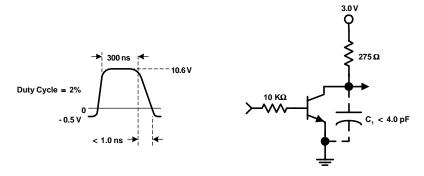


FIGURE 1: Delay and Rise Time Equivalent Test Circuit

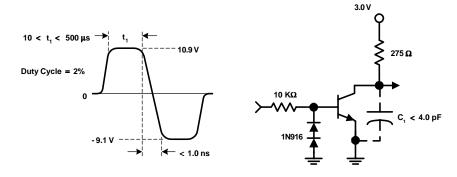


FIGURE 2: Storage and Fall Time Equivalent Test Circuit

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### 2N4123

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#### **General description**

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 100 mA.

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BUY

Product	Product status	Pb-free Status	Pricing*	Package type	Leads	Packing method	Package Marking Convention**
2N4123BU	Full Production	Full Production	\$0.0245	<u>TO-92</u>	3	BULK	Line 1: 2N Line 2: 4123 Line 3: -&3
2N4123TA	Full Production	Full Production	\$0.0245	<u>TO-92</u>	3	AMMO	Line 1: 2N Line 2: 4123 Line 3: -&3
2N4123TAR	Full Production	Full Production	\$0.0245	<u>TO-92</u>	3	AMMO	Line 1: 2N Line 2: 4123 Line 3: -&3
2N4123TF	Full Production		\$0.0245	<u>TO-92</u>	3	TAPE REEL	Line 1: 2N Line 2: 4123 Line 3: -&3

		Full Production					
2N4123TFR	Full Production	Full Production	\$0.0245	<u>TO-92</u>	3	TAPE REEL	Line 1: 2N Line 2: 4123 Line 3: -&3

<sup>\*</sup> Fairchild 1,000 piece Budgetary Pricing

\*\* A sample button will appear if the part is available through Fairchild's on-line samples program. If there is no sample button, please contact a Fairchild distributor to obtain samples



Indicates product with Pb-free second-level interconnect. For more information click here.

Package marking information for product 2N4123 is available. Click here for more information .

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#### Models

Package & leads	Condition	Software version	Revision date				
PSPICE							
TO-92-3	<u>Electrical</u>	25°C	N/A	N/A			

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## **Qualification Support**

Click on a product for detailed qualification data

Product
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<u>2N4123TA</u>
<u>2N4123TAR</u>
2N4123TF
<u>2N4123TFR</u>

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